NSN 5961-01-068-8833

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View Online at https://aerobasegroup.com/nsn/5961-01-068-8833 **Inclosure Material:** Metal **Overall Length:** Between 1.479 inches and 1.519 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **End Application:** Detecting set, infrared, an/aas-36 **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 collector to base voltage, dc and -100.0 collector to emitter voltage, dc and -5.0 emitter to base voltage, dc **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 96214-804211 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

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